NSN 5962-01-421-2479



Memory Microcircuit - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5962-01-421-2479 **Body Length:** 0.358 inches **Body Width:** 0.358 inches **Body Height:** 0.100 inches **Maximum Power Dissipation Rating:** 1.0 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** Pacer dawn **Features Provided:** Hermetically sealed and burn in and programmable and positive outputs and electrostatic sensitive **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Leadless flat pack **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 16 input **Criticality Code Justification:** Cbbl **Case Outline Source And Designator:** C-2 mil-m-38510 **Terminal Surface Treatment:** Solder **Product Name:** Microcircuit, programmed (pal 16l8a) Voltage Rating And Type Per Characteristic: -0.5 volts power source and 7.0 volts power source **Time Rating Per Chacteristic:** 30.00 nanoseconds propagation delay time, low to high level output and 30.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:**

Pal

Special Features:

Altered item, made from device 81036072x, cage 67268

Terminal Type And Quantity:

20 leadless

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Memory Microcircuit - Page 2 of 2



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N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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